AMENDMENTS TO THE CLAIMS

Please amend the Claims as follows:

1-6. (Canceled)

7. (Currently Amended) A light emitting diode comprising a pellet, a

major front surface of which, where an electrode is formed, is made of a GaAsP mixed

crystal, characterized in that the major front surface is a rough surface; and characterized

in that all side surfaces of the pellet are rough surfaces, wherein the rough surfaces are

formed with fine projections having a diameter in a range of 0.3 μm to 3 μm.

8 – 10. (Canceled)

11. (Currently Amended) A fabrication process for a light emitting diode

having a pellet, a major front surface of which, where an electrode is formed, is made of a

GaAsP mixed crystal, characterized in that the pellet is treated with an etching solution of

an aqueous solution containing Br₂, nitric acid, hydrofluoric acid and acetic acid or l₂,

nitric acid, hydrofluoric acid, and acetic acid to form fine projections on the major front

surface and all side surfaces of the pellet, wherein the fine projections have a diameter in

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a range of 0.3 μ m to 3 μ m.

12. (Canceled)

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13. (Previously Presented) A fabrication process for a light emitting diode according to claim 11, characterized in that the etching solution contains 40 to 80 parts of nitric acid, 40 to 300 parts of hydrofluoric acid and 400 to 2000 parts of acetic acid based on 1 part of Br₂ or l₂ in a molar ratio.

(Canceled) 14.